AIP Journal of Applied Physics

Publisher's Note: "Evolution of self-assembled type-II ZnTe/ZnSe nanostructures: Structural and electronic properties" [J. Appl. Phys. 111, 093524 (2012)]

S. J. Kim, B.-C. Juang, W. Wang, J. R. Jokisaari, C.-Y. Chen, J. D. Phillips, and X. Q. Pan

Citation: Journal of Applied Physics **112**, 019902 (2012); doi: 10.1063/1.4736735
View online: http://dx.doi.org/10.1063/1.4736735
View Table of Contents: http://scitation.aip.org/content/aip/journal/jap/112/1?ver=pdfcov
Published by the AIP Publishing

Publisher's Note: "Evolution of self-assembled type-II ZnTe/ZnSe nanostructures: Structural and electronic properties" [J. Appl. Phys. 111, 093524 (2012)]

S. J. Kim,[1,a)] B.-C. Juang,[2,a)] W. Wang,[2] J. R. Jokisaari,[1] C.-Y. Chen,[2] J. D. Phillips,[2,b)] and X. Q. Pan[1,b)]
[1]*Department of Materials Science and Engineering, Hayward St., Ann Arbor, Michigan 48109, USA*
[2]*Department of Electrical Engineering and Computer Science, Beal Avenue, Ann Arbor, Michigan 48109, USA*

(Received 9 May 2012; accepted 27 June 2012; published online 6 July 2012)

[http://dx.doi.org/10.1063/1.4736735]

This article was originally published online on 9 May 2012 with an error in author X. Q. Pan's name.

The author's name was correct in the printed version of the article. All online versions of the article were corrected on 11 May 2012.

[a)]These authors contributed equally to this work.
[b)]Authors to whom correspondence should be addressed. Electronic addresses: jphilli@umich.edu and panx@umich.edu.

